



High Efficient Surface Mount Rectifiers Reverse Voltage 50 to 1000 Volts Forward Current 1.0 Ampere

## **Features**

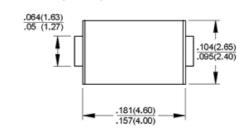
- Glass passivated junction chip.
- For surface mounted application
- Low forward voltage drop
- Low profile package
- Built-in stain relief, ideal for automatic placement
- Fast switching for high efficiency
- High temperature soldering: 250°C/10 seconds at terminals
- Plastic material used carries Underwriters Laboratory Classification 94V-O

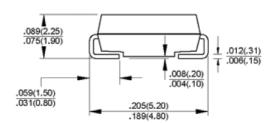
## Mechanical Data

- ◆ Cases: Molded plastic◆ Terminals: Solder plated
- ◆ Polarity: Indicated by cathode band
  ◆ Weight: 0.002 ounce, 0.064 gram



DO-214AC (SMA)





Dimensions in inches and (millimeters)

## **Maximum Ratings and Electrical Characteristics**

Ratings at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 60Hz, resistive or inductive load.

For capacitive load, derate current by 20%

Parameter	Symbols	HS1A	нѕ1в	HS1D	HS1F	HS1G	HS1J	нѕ1к	HS1M	Units
Maximum repetitive peak reverse voltage	V <sub>RRM</sub>	50	100	200	300	400	600	800	1000	Volts
Maximum RMS voltage	V <sub>RMS</sub>	35	70	140	210	280	420	560	700	Volts
Maximum DC blocking voltage	V <sub>DC</sub>	50	100	200	300	400	600	800	1000	Volts
Maximum average forward rectified current See Fig.2	I <sub>(AV)</sub>	1.0								Amp
Peak forward surge current, 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)	I <sub>FSM</sub>	30.0								Amps
Maximum instantaneous forward voltage @ 1.0A	V <sub>F</sub>	1.0 1.3 1.7					Volts			
Maximum DC reverse current $\textcircled{0}$ T <sub>A</sub> =25°C at rated DC blocking voltage $\textcircled{0}$ T <sub>A</sub> =100°C	I <sub>R</sub>	5.0 100								uA uA
Maximum reverse recovery time (Note 1)	ţ,,	50 75						nS		
Typical junction capacitance (Note 2)	CJ	20 15						pF		
Operating junction temperature range	T <sub>J</sub>	-55 to +150								°C
Storage temperature range	T <sub>STG</sub>	-55 to +150								°C

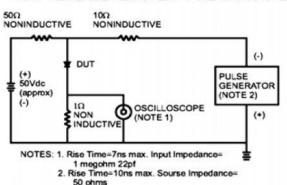
Notes: 1. Reverse Recovery Test Conditions: I<sub>E</sub>=0.5A, I<sub>R</sub>=1.0A, I<sub>RR</sub>=0.25A

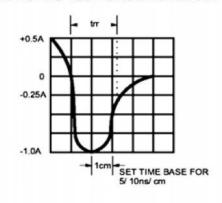
2. Measured at 1 MHz and Applied Reverse Voltage of 4.0 V D.C.



## RATINGS AND CHARACTERISTIC CURVES

FIG.1- REVERSE RECOVERY TIME CHARACTERISTIC AND TEST CIRCUIT DIAGRAM



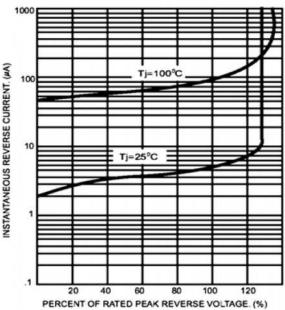


AVERAGE FORWARD CURRENT. (A) 0.5 Half Wave 60Hz Resistive or Inductive Load 50 75 100 125 150

LEAD TEMPERATURE. (°C)

FIG.2- MAXIMUM AVERAGE FORWARD CURRENT DERATING

FIG.3- TYPICAL REVERSE CHARACTERISTICS



CURRENT

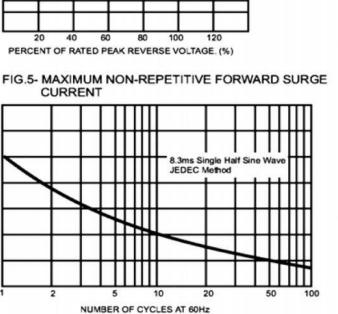
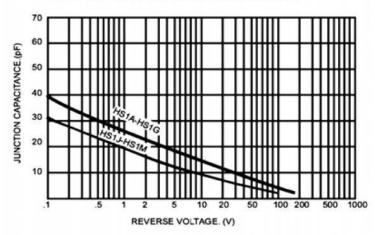


FIG.4- TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS 100 3 Tj=25°C INSTANTANEOUS FORWARD CURRENT. 10 0. 0.01 1.0 1.2 FORWARD VOLTAGE. (V)

FIG.6- TYPICAL JUNCTION CAPACITANCE



PEAK FORWARD SURGE CURRENT. (A)

35

30

25

20

15 10